NSN 5962-01-214-5320

Memory Microcircuit - Page 1 of 1



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Body Length: 1.200 inches Body Width: 0.295 inches Body Height: 0.120 inches Maximum Power Dissipation Rating: 1.10 watts Operating Tempurature Range: -55.0 to 125.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius Features Provided: Hermetically sealed and monolithic and low power Inclosure Material: Ceramic Inclosure Configuration: Dual-in-line Output Logic Form: Complementary-metal oxide-semiconductor logic Input Crucit Pattern: 16 input Solder Voltage Rating And Type Per Characteristic: Solder Voltage Rating And Type Per Characteristic: Solder Brow poweris-dated (includes industry or association standards, individual manufactureer standards, etc.). Terminal Type And Quantity: 24 printed circuit
Body Width: 0.295 inches Body Height: 0.120 inches Maximum Power Dissipation Rating: 1.0 watts Operating Tempurature Range: -55.0 to 125.0 degrees celsius Storage Tempurature Range: -55.0 to 50.0 degrees celsius Features Provided: Hernetically sealed and monolithic and low power Inclosure Material: Ceramic Dual-inline Output Logic Form: Complementary-metal oxide-semiconductor logic Input Circuit Pattern: Solder Voltage Rating And Type Per Characteristic: S.5 volts power source Memory Device Type: Ram Testaba Document: 9600-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). Terminal Type And Quantity: 24 printed circuit Shoft Life: Na
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Terminal Type And Quantity: 24 printed circuit Shelf Life: N/a
24 printed circuit Shelf Life: N/a
Shelf Life: N/a
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
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